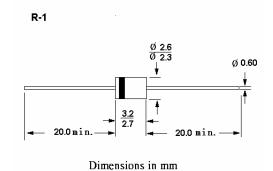
1A1S THRU 1A7S

SILICON RECTIFIERS Reverse Voltage – 50 to 1000 Volts Forward Current – 1.0 Amperes



Features

- High reliability
- Low leakage
- Low forward voltage drop
- High current capability

Mechanical Data

- Case: Molded plastic black body
- Mounting Position: Any
- Lead: MIL-STD 202E method 208C guaranteed

Absolute Maximum Ratings and Characteristics

Ratings at 25°Cambient temperature unless otherwise specified.Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

		Symbols	1A1S	1A2S	1A3S	1A4S	1A5S	1A6S	1A7S	Units
Maximum repetitive peak reverse voltage		V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage		V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage		V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at $T_A = 25$ $^{\circ}C$		Ι _ο	1							А
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)		I _{FSM}	25							A
Maximum instantaneous forward voltage at 1A DC		V _F	1.1						V	
Maximum DC reverse current at rated DC blocking voltage	$@T_{A} = 25^{\circ}C$	I _R	5							uA
	$@T_A = 100^{\circ}C$		50							
Maximum full load reverse current full cycle average 0.375" (9.5mm) lead length at $T_L=75^{\circ}C$			100							uA
Typical junction capacitance at 4 V, 1MHz		CJ	15						pF	
Typical thermal resistance		$R_{ ext{ heta}JA}$	60						^o C/W	
Operating and storage temperature range		T _J ,T _S	-65 to +150							°C

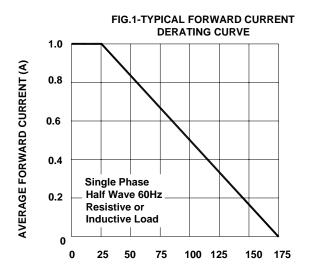


SEMTECH ELECTRONICS LTD. (Subsidiary of Sino-Tech International Holdings Limited, a company listed on the Hong Kong Stock Exchange, Stock Code: 724)



Dated : 23/12/2003

RATING AND CHARACTERISTIC CURVES (1A1S thru 1A7S)



AMBIENT TEMPERATURE(°C)

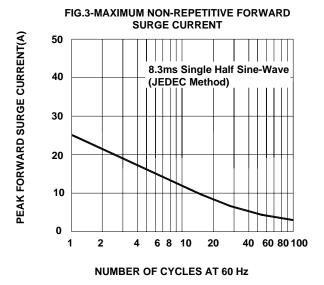
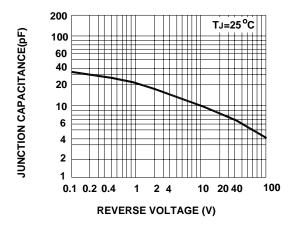


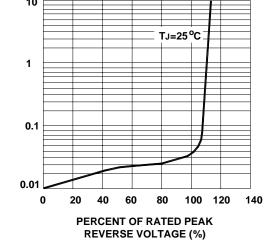
FIG.5-TYPICAL JUNCTION CAPACITANCE





SEMTECH ELECTRONICS LTD. (Subsidiary of Sino-Tech International Holdings Limited, a company listed on the Hong Kong Stock Exchange, Stock Code: 724)

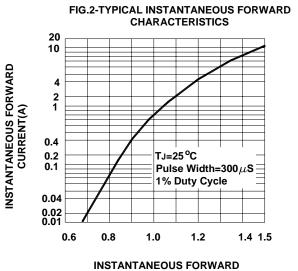






NSTANTANEOUS REVERSE CURRENT(*µ***A**)

FIG.4-TYPICAL REVERSE CHARACTERISTICS



VOLTAGE(V)

Dated : 23/12/2003